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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

Details

Product Status	Active
Core Processor	PIC
Core Size	8-Bit
Speed	20MHz
Connectivity	<u>.</u>
Peripherals	POR, WDT
Number of I/O	20
Program Memory Size	3KB (2K x 12)
Program Memory Type	OTP
EEPROM Size	<u>.</u>
RAM Size	72 x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	
Oscillator Type	External
Operating Temperature	0°C ~ 70°C (TA)
Mounting Type	Surface Mount
Package / Case	28-SSOP (0.209", 5.30mm Width)
Supplier Device Package	28-SSOP
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic16c57ct-20-ss

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

NOTES:

TABLE 1-1: PIC16C5X FAMILY OF DEVICES

Features	PIC16C54	PIC16CR54	PIC16C55	PIC16C56	PIC16CR56
Maximum Operation Frequency	40 MHz	20 MHz	40 MHz	40 MHz	20 MHz
EPROM Program Memory (x12 words)	512	_	512	1K	
ROM Program Memory (x12 words)		512	_	_	1K
RAM Data Memory (bytes)	25	25	24	25	25
Timer Module(s)	TMR0	TMR0	TMR0	TMR0	TMR0
I/O Pins	12	12	20	12	12
Number of Instructions	33	33	33	33	33
Packages	18-pin DIP, SOIC; 20-pin SSOP	18-pin DIP, SOIC; 20-pin SSOP	28-pin DIP, SOIC; 28-pin SSOP	18-pin DIP, SOIC; 20-pin SSOP	18-pin DIP, SOIC; 20-pin SSOP

PIC16C58 Features **PIC16C57** PIC16CR57 PIC16CR58 Maximum Operation Frequency 20 MHz 40 MHz 40 MHz 20 MHz EPROM Program Memory (x12 words) 2K 2K ____ _ ROM Program Memory (x12 words) 2K 2K _ _ RAM Data Memory (bytes) 72 72 73 73 Timer Module(s) TMR0 TMR0 TMR0 TMR0 I/O Pins 20 20 12 12 Number of Instructions 33 33 33 33 28-pin DIP, SOIC; 28-pin DIP, SOIC; 18-pin DIP, SOIC; 18-pin DIP, SOIC; Packages 28-pin SSOP 28-pin SSOP 20-pin SSOP 20-pin SSOP All PIC® Family devices have Power-on Reset, selectable Watchdog Timer, selectable Code Protect and high I/O current capability.

3.1 **Clocking Scheme/Instruction** Cycle

The clock input (OSC1/CLKIN pin) is internally divided by four to generate four non-overlapping quadrature clocks, namely Q1, Q2, Q3 and Q4. Internally, the program counter is incremented every Q1 and the instruction is fetched from program memory and latched into the instruction register in Q4. It is decoded and executed during the following Q1 through Q4. The clocks and instruction execution flow are shown in Figure 3-2 and Example 3-1.

3.2 Instruction Flow/Pipelining

An Instruction Cycle consists of four Q cycles (Q1, Q2, Q3 and Q4). The instruction fetch and execute are pipelined such that fetch takes one instruction cycle, while decode and execute takes another instruction cycle. However, due to the pipelining, each instruction effectively executes in one cycle. If an instruction causes the program counter to change (e.g., GOTO), then two cycles are required to complete the instruction (Example 3-1).

A fetch cycle begins with the program counter (PC) incrementing in Q1.

In the execution cycle, the fetched instruction is latched into the Instruction Register in cycle Q1. This instruction is then decoded and executed during the Q2, Q3 and Q4 cycles. Data memory is read during Q2 (operand read) and written during Q4 (destination write).

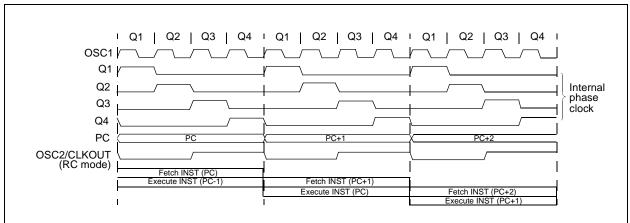
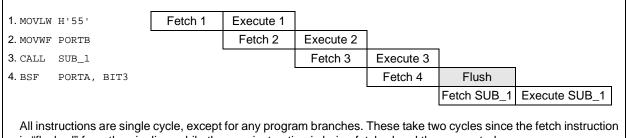


FIGURE 3-2: **CLOCK/INSTRUCTION CYCLE**

EXAMPLE 3-1: INSTRUCTION PIPELINE FLOW



is "flushed" from the pipeline, while the new instruction is being fetched and then executed.

PIC16C5X

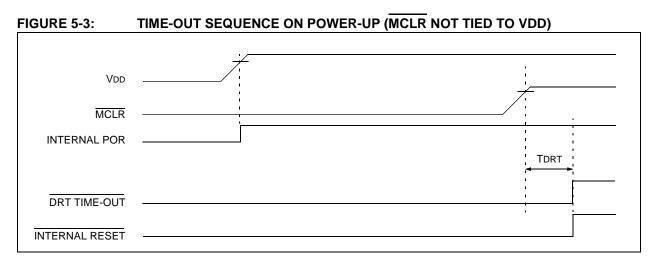


FIGURE 5-4: TIME-OUT SEQUENCE ON POWER-UP (MCLR TIED TO VDD): FAST VDD RISE TIME

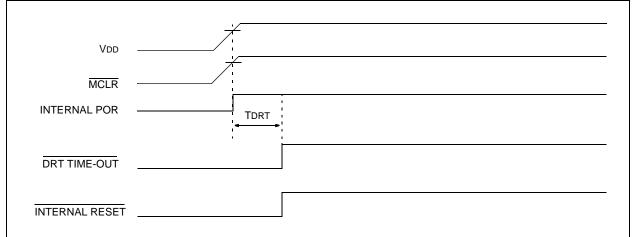
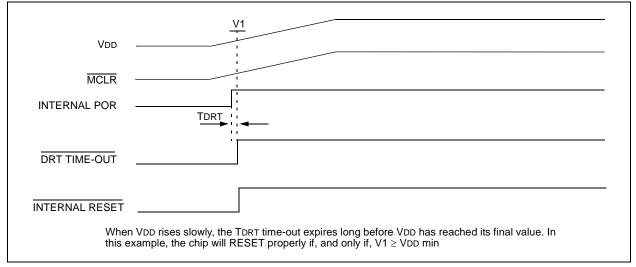


FIGURE 5-5: TIME-OUT SEQUENCE ON POWER-UP (MCLR TIED TO VDD): SLOW VDD RISE TIME



11.8 MPLAB ICD In-Circuit Debugger

Microchip's In-Circuit Debugger, MPLAB ICD, is a powerful, low cost, run-time development tool. This tool is based on the FLASH PIC MCUs and can be used to develop for this and other PIC microcontrollers. The MPLAB ICD utilizes the in-circuit debugging capability built into the FLASH devices. This feature, along with Microchip's In-Circuit Serial ProgrammingTM protocol, offers cost-effective in-circuit FLASH debugging from the graphical user interface of the MPLAB Integrated Development Environment. This enables a designer to develop and debug source code by watching variables, single-stepping and setting break points. Running at full speed enables testing hardware in real-time.

11.9 PRO MATE II Universal Device Programmer

The PRO MATE II universal device programmer is a full-featured programmer, capable of operating in Stand-alone mode, as well as PC-hosted mode. The PRO MATE II device programmer is CE compliant.

The PRO MATE II device programmer has programmable VDD and VPP supplies, which allow it to verify programmed memory at VDD min and VDD max for maximum reliability. It has an LCD display for instructions and error messages, keys to enter commands and a modular detachable socket assembly to support various package types. In Stand-alone mode, the PRO MATE II device programmer can read, verify, or program PIC devices. It can also set code protection in this mode.

11.10 PICSTART Plus Entry Level Development Programmer

The PICSTART Plus development programmer is an easy-to-use, low cost, prototype programmer. It connects to the PC via a COM (RS-232) port. MPLAB Integrated Development Environment software makes using the programmer simple and efficient.

The PICSTART Plus development programmer supports all PIC devices with up to 40 pins. Larger pin count devices, such as the PIC16C92X and PIC17C76X, may be supported with an adapter socket. The PICSTART Plus development programmer is CE compliant.

11.11 PICDEM 1 Low Cost PIC MCU Demonstration Board

The PICDEM 1 demonstration board is a simple board which demonstrates the capabilities of several of Microchip's microcontrollers. The microcontrollers supported are: PIC16C5X (PIC16C54 to PIC16C58A). PIC16C61, PIC16C62X, PIC16C71, PIC16C8X, PIC17C42, PIC17C43 and PIC17C44. All necessary hardware and software is included to run basic demo programs. The user can program the sample microcontrollers provided with the PICDEM 1 demonstration board on a PRO MATE II device programmer, or a PICSTART Plus development programmer, and easily test firmware. The user can also connect the PICDEM 1 demonstration board to the MPLAB ICE incircuit emulator and download the firmware to the emulator for testing. A prototype area is available for the user to build some additional hardware and connect it to the microcontroller socket(s). Some of the features include an RS-232 interface, a potentiometer for simulated analog input, push button switches and eight LEDs connected to PORTB.

11.12 PICDEM 2 Low Cost PIC16CXX Demonstration Board

The PICDEM 2 demonstration board is a simple demonstration board that supports the PIC16C62, PIC16C64, PIC16C65, PIC16C73 and PIC16C74 microcontrollers. All the necessary hardware and software is included to run the basic demonstration programs. The user can program the sample microcontrollers provided with the PICDEM 2 demonstration board on a PRO MATE II device programmer, or a PICSTART Plus development programmer, and easily test firmware. The MPLAB ICE in-circuit emulator may also be used with the PICDEM 2 demonstration board to test firmware. A prototype area has been provided to the user for adding additional hardware and connecting it to the microcontroller socket(s). Some of the features include a RS-232 interface, push button switches, a potentiometer for simulated analog input, a serial EEPROM to demonstrate usage of the I^2C^{TM} bus and separate headers for connection to an LCD module and a keypad.

FIGURE 12-5: TIMER0 CLOCK TIMINGS - PIC16C54/55/56/57

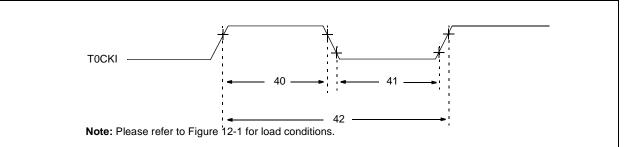


TABLE 12-4: TIMER0 CLOCK REQUIREMENTS - PIC16C54/55/56/57

$\label{eq:AC Characteristics} \begin{tabular}{lllllllllllllllllllllllllllllllllll$)	
Param No.	Symbol	Characteristic	Characteristic Min Typ† Max Units Co				
40	Tt0H	T0CKI High Pulse Width - No Prescaler - With Prescaler	0.5 Tcy + 20* 10*		_	ns ns	
41	Tt0L	T0CKI Low Pulse Width - No Prescaler - With Prescaler	0.5 Tcy + 20* 10*		_	ns ns	
42	Tt0P	T0CKI Period	20 or <u>Tcy + 40</u> * N			ns	Whichever is greater. N = Prescale Value (1, 2, 4,, 256)

* These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

13.2 DC Characteristics: PIC16CR54A-04E, 10E, 20E (Extended)

				Standard Operating Conditions (unless otherwise specifiedOperating Temperature $-40^{\circ}C \le TA \le +125^{\circ}C$ for extended				
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions	
D001	Vdd	Supply Voltage RC, XT and LP modes HS mode	3.25 4.5		6.0 5.5	V V		
D002	Vdr	RAM Data Retention Voltage ⁽¹⁾	—	1.5*	—	V	Device in SLEEP mode	
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	—	Vss	—	V	See Section 5.1 for details on Power-on Reset	
D004	Svdd	VDD Rise Rate to ensure Power- on Reset	0.05*	_		V/ms	See Section 5.1 for details on Power-on Reset	
D010	IDD	Supply Current ⁽²⁾ RC ⁽³⁾ and XT modes HS mode HS mode		1.8 4.8 9.0	3.3 10 20	mA mA mA	Fosc = 4.0 MHz, Vdd = 5.5V Fosc = 10 MHz, Vdd = 5.5V Fosc = 16 MHz, Vdd = 5.5V	
D020	IPD	Power-down Current ⁽²⁾		5.0 0.8	22 18	μΑ μΑ	VDD = 3.25V, WDT enabled VDD = 3.25V, WDT disabled	

These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.

- 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, TOCKI = VDD, MCLR = VDD; WDT enabled/ disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
- 3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in kΩ.

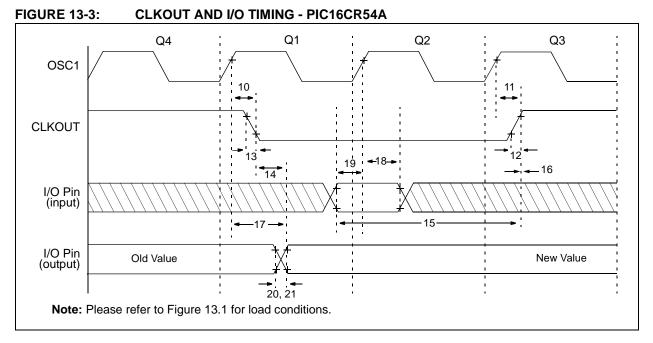


TABLE 13-2: CLKOUT AND I/O TIMING REQUIREMENTS - PIC16CR54A

AC Chara	acteristics							
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units		
10	TosH2ckL	OSC1↑ to CLKOUT↓ ⁽¹⁾	—	15	30**	ns		
11	TosH2ckH	OSC1↑ to CLKOUT↑ ⁽¹⁾	—	15	30**	ns		
12	TckR	CLKOUT rise time ⁽¹⁾	—	5.0	15**	ns		
13	TckF	CLKOUT fall time ⁽¹⁾	—	5.0	15**	ns		
14	TckL2ioV	CLKOUT↓ to Port out valid ⁽¹⁾	—	—	40**	ns		
15	TioV2ckH	Port in valid before CLKOUT ⁽¹⁾	0.25 TCY+30*	—		ns		
16	TckH2iol	Port in hold after CLKOUT ⁽¹⁾	0*	—		ns		
17	TosH2ioV	OSC1↑ (Q1 cycle) to Port out valid ⁽²⁾	—	—	100*	ns		
18	TosH2iol	OSC1 [↑] (Q2 cycle) to Port input invalid (I/O in hold time)	TBD	—	—	ns		
19	TioV2osH	Port input valid to OSC1↑ (I/O in setup time)	TBD	—	—	ns		
20	TioR	Port output rise time ⁽²⁾	_	10	25**	ns		
21	TioF	Port output fall time ⁽²⁾	_	10	25**	ns		

* These parameters are characterized but not tested.

- ** These parameters are design targets and are not tested. No characterization data available at this time.
- † Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: Measurements are taken in RC Mode where CLKOUT output is 4 x Tosc.

2: Please refer to Figure 13.1 for load conditions.

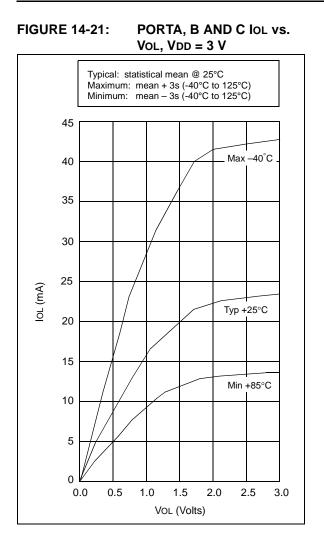
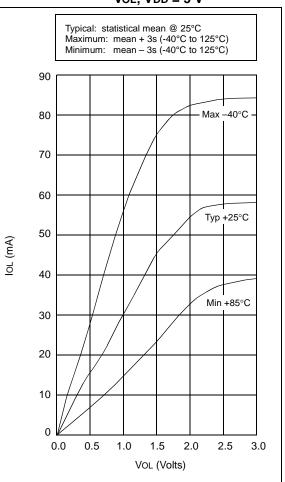


FIGURE 14-22: PORTA, B AND C IOL vs. VoL, VDD = 5 V



15.2 DC Characteristics: PIC16C54A-04E, 10E, 20E (Extended) PIC16LC54A-04E (Extended)

		FICTULCJ			cnac	ч)	
PIC16LC54A-04E (Extended)				ard Ope ting Terr			tions (unless otherwise specified) $-40^{\circ}C \le TA \le +125^{\circ}C$ for extended
PIC16C (Extend		10E, 20E		ard Ope ting Terr			tions (unless otherwise specified) $-40^{\circ}C \le TA \le +125^{\circ}C$ for extended
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions
	Vdd	Supply Voltage			•		
D001		PIC16LC54A	3.0 2.5	_	6.25 6.25	V V	XT and RC modes LP mode
D001A		PIC16C54A	3.5 4.5		5.5 5.5	V V	RC and XT modes HS mode
D002	Vdr	RAM Data Retention Voltage ⁽¹⁾	—	1.5*	-	V	Device in SLEEP mode
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	—	Vss	-	V	See Section 5.1 for details on Power-on Reset
D004	Svdd	VDD Rise Rate to ensure Power-on Reset	0.05*	_	_	V/ms	See Section 5.1 for details on Power-on Reset
	IDD	Supply Current ⁽²⁾					
D010		PIC16LC54A	—	0.5	25	mA	Fosc = 4.0 MHz, VDD = 5.5V, RC ⁽³⁾ and XT modes
			—	11	27	μA	Fosc = 32 kHz, VDD = 2.5V, LP mode, Commercial
			—	11	35	μA	Fosc = 32 kHz, VDD = 2.5V, LP mode, Industrial
			_	11	37	μA	Fosc = 32 kHz, VDD = 2.5V, LP mode, Extended
D010A		PIC16C54A	—	1.8	3.3	mA	Fosc = 4.0 MHz, VDD = 5.5V, $RC^{(3)}$ and XT modes
			—	4.8	10	mA	Fosc = 10 MHz, VDD = 5.5V, HS mode
			—	9.0	20	mA	Fosc = 20 MHz, VDD = 5.5V, HS mode

Legend: Rows with standard voltage device data only are shaded for improved readability.

- * These parameters are characterized but not tested.
- † Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.
- Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
 - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, TOCKI = VDD, MCLR = VDD; WDT enabled/ disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
 - **3:** Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in kΩ.

15.6 Timing Diagrams and Specifications

FIGURE 15-2: EXTERNAL CLOCK TIMING - PIC16C54A

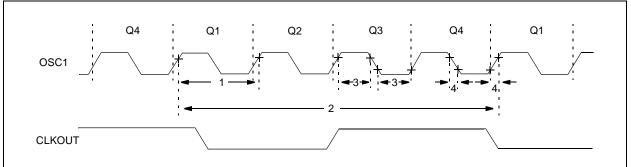


TABLE 15-1: EXTERNAL CLOCK TIMING REQUIREMENTS - PIC16C54A
--

AC Chara	cteristics	Standard Operating Con Operating Temperature	0°0 -40°0 -20°0	$C \le TA \le +7$ $C \le TA \le +8$	0°C for c 5°C for ii 5°C for ii	ommer ndustria ndustria	rcial al al - PIC16LV54A-021	
Param No.	Symbol	Characteristic	Characteristic Min Typ† Max Units Conditions					
	Fosc	External CLKIN Fre-	DC	_	4.0	MHz	XT OSC mode	
		quency ⁽¹⁾	DC	—	2.0	MHz	XT osc mode (PIC16LV54A)	
			DC	—	4.0	MHz	HS osc mode (04)	
			DC	—	10	MHz	HS osc mode (10)	
			DC	—	20	MHz	HS osc mode (20)	
			DC	—	200	kHz	LP OSC mode	
		Oscillator Frequency ⁽¹⁾	DC		4.0	MHz	RC osc mode	
			DC	—	2.0	MHz	RC osc mode (PIC16LV54A)	
			0.1	—	4.0	MHz	XT OSC mode	
			0.1	—	2.0	MHz	XT osc mode (PIC16LV54A)	
			4.0	—	4.0	MHz	HS osc mode (04)	
			4.0	—	10	MHz	HS osc mode (10)	
			4.0	—	20	MHz	HS osc mode (20)	
			5.0	—	200	kHz	LP osc mode	

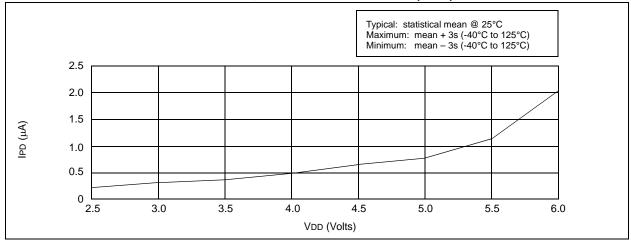
* These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

- Note 1: All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption. When an external clock input is used, the "max" cycle time limit is "DC" (no clock) for all devices.
 - Instruction cycle period (TcY) equals four times the input oscillator time base period.

PIC16C5X

FIGURE 16-5: TYPICAL IPD vs. VDD, WATCHDOG DISABLED (25°C)







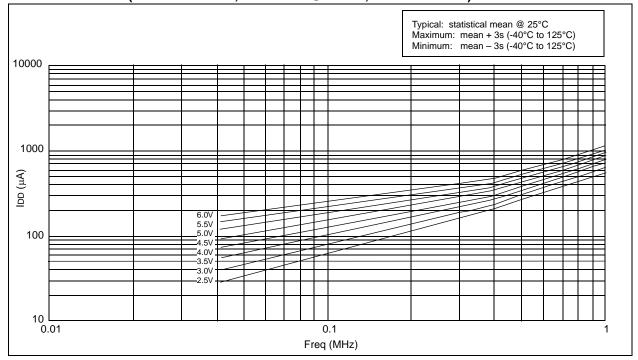
 Typical: statistical mean @ 25°C.

 Maximum: mean + 3s (-40°C to 125°C)

 Minimum: mean - 3s (-40°C to 125°C)
</tr

FIGURE 16-14: TYPICAL IDD vs. FREQUENCY (WDT DISABLED, RC MODE @ 300 PF, 25°C)

FIGURE 16-15: MAXIMUM IDD vs. FREQUENCY (WDT DISABLED, RC MODE @ 300 PF, -40°C to +85°C)



17.1 DC Characteristics:PIC16C54C/C55A/C56A/C57C/C58B-04, 20 (Commercial, Industrial) PIC16LC54C/LC55A/LC56A/LC57C/LC58B-04 (Commercial, Industrial) PIC16CR54C/CR56A/CR57C/CR58B-04, 20 (Commercial, Industrial) PIC16LCR54C/LCR56A/LCR57C/LCR58B-04 (Commercial, Industrial)

PIC16LC5X PIC16LCR5X (Commercial, Industrial)				Standard Operating Conditions (unless otherwise specified)Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial $-40^{\circ}C \le TA \le +85^{\circ}C$ for industrialStandard Operation Conditions (unless otherwise specified)						
PIC16C5X PIC16CR5X (Commercial, Industrial)				$\begin{array}{llllllllllllllllllllllllllllllllllll$						
Param No.	Symbol	Characteristic/Device	Min	Тур†	Max	Units	Conditions			
	Vdd	Supply Voltage								
D001		PIC16LC5X	2.5 2.7 2.5		5.5 5.5 5.5	V V V	$\begin{array}{l} -40^{\circ}C \leq TA \leq +\ 85^{\circ}C,\ 16LCR5X \\ -40^{\circ}C \leq TA \leq 0^{\circ}C,\ 16LC5X \\ 0^{\circ}C \leq TA \leq +\ 85^{\circ}C\ 16LC5X \end{array}$			
D001A		PIC16C5X	3.0 4.5	_	5.5 5.5	V V	RC, XT, LP and HS mode from 0 - 10 MHz from 10 - 20 MHz			
D002	Vdr	RAM Data Retention Volt- age ⁽¹⁾	—	1.5*	—	V	Device in SLEEP mode			
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	—	Vss	—	V	See Section 5.1 for details on Power-on Reset			
D004	SVDD	VDD Rise Rate to ensure Power-on Reset	0.05*	—	—	V/ms	See Section 5.1 for details on Power-on Reset			

Legend: Rows with standard voltage device data only are shaded for improved readability.

* These parameters are characterized but not tested.

- † Data in "Typ" column is at 5V, 25°C, unless otherwise stated. These parameters are for design guidance only, and are not tested.
- Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
 - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
 - **3:** Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in k Ω .

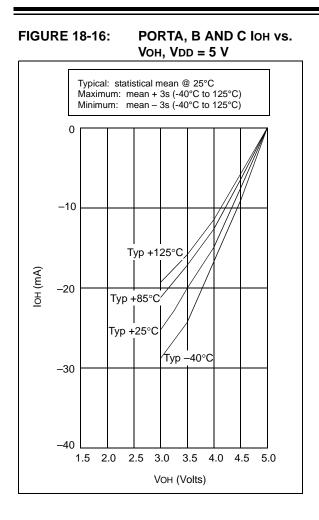
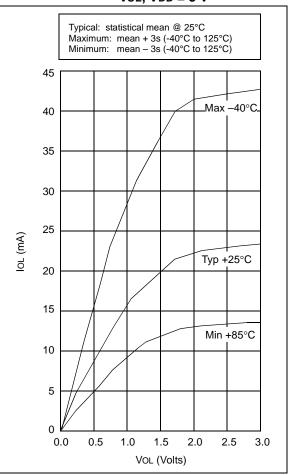


FIGURE 18-17: PORTA, B AND C IOL vs. Vol, VDD = 3 V



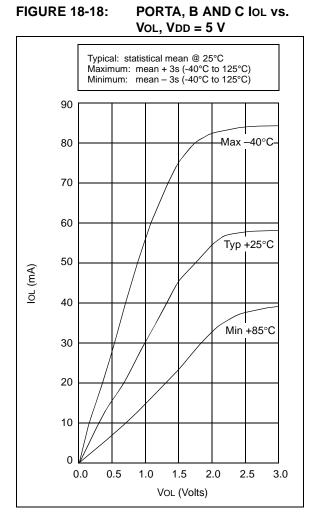


TABLE 18-2:INPUT CAPACITANCE

Pin	Typical Capacitance (pF)				
Pin	18L PDIP	18L SOIC			
RA port	5.0	4.3			
RB port	5.0	4.3			
MCLR	17.0	17.0			
OSC1	4.0	3.5			
OSC2/CLKOUT	4.3	3.5			
тоскі	3.2	2.8			

All capacitance values are typical at 25° C. A part-to-part variation of ±25% (three standard deviations) should be taken into account.

19.4 **Timing Diagrams and Specifications**

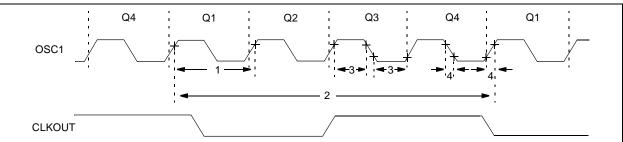


FIGURE 19-3: EXTERNAL CLOCK TIMING - PIC16C5X-40

EXTERNAL CLOCK TIMING REQUIREMENTS - PIC16C5X-40 TABLE 19-1:

AC Chara	cteristics	Standard Operating Conditions (unless otherwise specified)Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial						
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions	
	Fosc	External CLKIN Frequency ⁽¹⁾	20	_	40	MHz	HS osc mode	
1	Tosc	External CLKIN Period ⁽¹⁾	25	_	_	ns	HS OSC mode	
2	Тсу	Instruction Cycle Time ⁽²⁾	_	4/Fosc	_	—		
3	TosL, TosH	Clock in (OSC1) Low or High Time	6.0*	_	_	ns	HS oscillator	
4	TosR, TosF	Clock in (OSC1) Rise or Fall Time	—	_	6.5*	ns	HS oscillator	

- * These parameters are characterized but not tested.
- † Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.
- Note 1: All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption. When an external clock input is used, the "max" cycle time limit is "DC" (no clock) for all devices.

 - 2: Instruction cycle period (TCY) equals four times the input oscillator time base period.

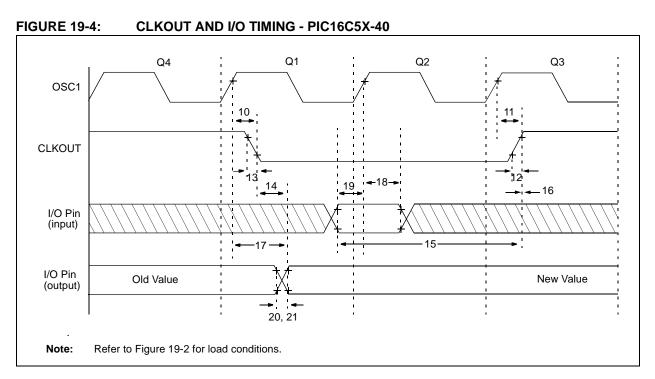


TABLE 19-2 :	CLKOUT AND I/O TIMING REQUIREMENTS - PIC16C5X-40

AC Characteristics		Standard Operating Conditions (unless otherwise specified)Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial							
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units			
10	TosH2ckL	OSC1↑ to CLKOUT↓ ^(1,2)	—	15	30**	ns			
11	TosH2ckH	OSC1↑ to CLKOUT↑ ^(1,2)	—	15	30**	ns			
12	TckR	CLKOUT rise time ^(1,2)	—	5.0	15**	ns			
13	TckF	CLKOUT fall time ^(1,2)	—	5.0	15**	ns			
14	TckL2ioV	CLKOUT↓ to Port out valid ^(1,2)	—	—	40**	ns			
15	TioV2ckH	Port in valid before CLKOUT ^(1,2)	0.25 TCY+30*	—	_	ns			
16	TckH2iol	Port in hold after CLKOUT ^(1,2)	0*	—	_	ns			
17	TosH2ioV	OSC1 [↑] (Q1 cycle) to Port out valid ⁽²⁾	—	—	100	ns			
18	TosH2iol	OSC1 [↑] (Q2 cycle) to Port input invalid (I/O in hold time)	TBD	—	—	ns			
19	TioV2osH	Port input valid to OSC1↑ (I/O in setup time)	TBD	—	—	ns			
20	TioR	Port output rise time ⁽²⁾	—	10	25**	ns			
21	TioF	Port output fall time ⁽²⁾	—	10	25**	ns			

* These parameters are characterized but not tested.

- ** These parameters are design targets and are not tested. No characterization data available at this time.
- † Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: Measurements are taken in RC Mode where CLKOUT output is 4 x Tosc.

2: Refer to Figure 19-2 for load conditions.

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20.0 DEVICE CHARACTERIZATION - PIC16LC54C 40MHz

The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

"Typical" represents the mean of the distribution at 25°C. "Maximum" or "minimum" represents (mean + 3σ) or (mean - 3σ) respectively, where σ is a standard deviation, over the whole temperature range.





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28-Lead Plastic Dual In-line (P) - 600 mil (PDIP)

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units	INCHES*			MILLIMETERS			
Dimer	ision Limits	MIN	NOM	MAX	MIN	NOM	MAX	
Number of Pins	n		28			28		
Pitch	р		.100			2.54		
Top to Seating Plane	А	.160	.175	.190	4.06	4.45	4.83	
Molded Package Thickness	A2	.140	.150	.160	3.56	3.81	4.06	
Base to Seating Plane	A1	.015			0.38			
Shoulder to Shoulder Width	E	.595	.600	.625	15.11	15.24	15.88	
Molded Package Width	E1	.505	.545	.560	12.83	13.84	14.22	
Overall Length	D	1.395	1.430	1.465	35.43	36.32	37.21	
Tip to Seating Plane	L	.120	.130	.135	3.05	3.30	3.43	
Lead Thickness	С	.008	.012	.015	0.20	0.29	0.38	
Upper Lead Width	B1	.030	.050	.070	0.76	1.27	1.78	
Lower Lead Width	В	.014	.018	.022	0.36	0.46	0.56	
Overall Row Spacing	§ eB	.620	.650	.680	15.75	16.51	17.27	
Mold Draft Angle Top	α	5	10	15	5	10	15	
Mold Draft Angle Bottom	β	5	10	15	5	10	15	

* Controlling Parameter § Significant Characteristic

Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.

JEDEC Equivalent: MO-011 Drawing No. C04-079